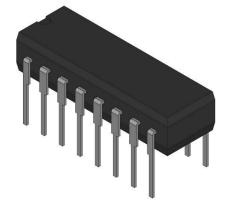


SNJ54HC112J Datasheet

www.digi-electronics.com



0	DiGi Electronics Part Number
1	Manufacturer
-	Manufacturer Product Number
<u>r</u>	Description
F	Detailed Description

SNJ54HC112J-DG Texas Instruments SNJ54HC112J 54HC112 DUAL J-K NEGATIVE-EDGE-T Flip Flop Element Bit

https://www.DiGi-Electronics.com



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Purchase and inquiry

Environmental & Export classification

ECCN:

EAR99

HTSUS:

8542.39.0001



Texas Instruments

SNx4HC112 Dual J-K Negative-Edge-Triggered Flip-Flops With Clear and Preset

1 Features

- Wide operating voltage range of 2V to 6V
- Outputs can drive up to 10 LSTTL loads
- Low power consumption, 40 μA max I_{CC}
- Typical t_{pd} = 13ns
- ±4mA output drive at 5V
- Low input current of 1µA max

2 Applications

- Servers
- LED displays
- Network switch
- Telecom infrastructure
- Motor drivers
- I/O expanders

3 Description

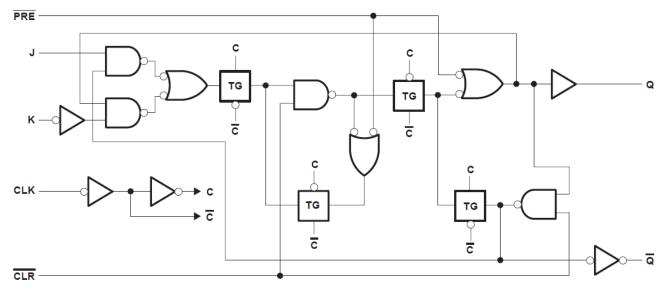
The SNx4HC112 devices contain two independent J-K negative-edge-triggered flip-flops. A low level at the preset (\overline{PRE}) or clear (\overline{CLR}) inputs sets or resets the outputs, regardless of the levels of the other inputs. When \overline{PRE} and \overline{CLR} are inactive (high), data at the J and K inputs meeting the setup time requirements are transferred to the outputs on the negative-going edge of the clock (CLK) pulse. Clock triggering occurs at a voltage level and is not directly related to the fall time of the CLK pulse. Following the hold-time interval, data at the J and K inputs may be changed without affecting the levels at the outputs. These versatile flipflops perform as toggle flip-flops by tying J and K high.

Device Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾	BODY SIZE (NOM) ⁽³⁾								
	J (CDIP, 16)	19.56mm × 6.92mm	19.56mm × 6.92mm								
	D (SOIC, 16)	9.9mm × 6mm	9.9mm × 3.9mm								
SNx4HC112	N (PDIP, 16)	19.3mm × 9.4mm	19.3mm × 6.35mm								
	FK (LCCC, 20)	8.89mm × 8.89mm	8.89mm × 8.89mm								
	W (CFP, 16)	10.3mm × 6.73mm	10.3mm × 6.73mm								

(1) For more information, see Section 11

- (2) The package size (length × width) is a nominal value and includes pins, where applicable.
- (3) The body size (length × width) is a nominal value and does not include pins.



Functional Block Diagram



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4 Pin Configuration and Functions

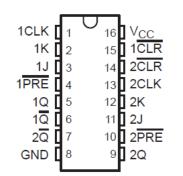
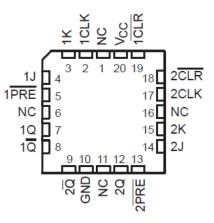


Figure 4-1. J, D, N, W Package, 16-Pin CDIP, SOIC, PDIP, CFP (Top View)



NC - No internal connection

Figure 4-2. FK Package, 20-Pin LCCC (Top View)



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage range	-0.5	7	V	
I _{IK}	Input clamp current ⁽²⁾	$V_{I} < 0 \text{ or } V_{I} > V_{CC}$		±20	mA
I _{OK}	Output clamp current ⁽²⁾	V_{O} < 0 or V_{O} > V_{CC}		±20	mA
lo	Continuous output current	$V_{O} = 0$ to V_{CC}		±25	mA
	Continuous current through V_{CC} or GND			±50	mA
TJ	Junction temperature		150	°C	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

5.2 Recommended Operating Conditions (2)

			SN	54HC112		SN	74HC112			
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT	
V _{CC}	Supply voltage		2	5	6	2	5	6	V	
		V _{CC} = 2V	1.5			1.5				
V _{IH}	High-level input voltage	V _{CC} = 4.5V	3.15			3.15			V	
		V _{CC} = 6V	4.2			4.2				
V _{IL}	Low-level input voltage	$V_{CC} = 2V$			0.5			0.5	V	
		V _{CC} = 4.5V			1.35			1.35		
		V _{CC} = 6V			1.8			1.8		
VI	Input voltage		0		V _{CC}	0		V _{CC}	V	
Vo	Output voltage		0		V _{CC}	0		V _{CC}	V	
		$V_{CC} = 2V$			1000			1000		
t _t (1)	Input transition (rise and fall) time	V _{CC} = 4.5V			500			500	ns	
		V _{CC} = 6V			400			400		
T _A	Operating free-air temperature		-55		125	-40		85	°C	

(1) If this device is used in the threshold region (from V_{IL}max = 0.5V to V_{IH}min = 1.5V), there is a potential to go into the wrong state from induced grounding, causing double clocking. Operating with the inputs at t_t = 1000ns and V_{CC} = 2V does not damage the device; however, functionally, the CLK inputs are not ensured while in the shift, count, or toggle operating modes.

(2) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

SN54HC112, SN74HC112

SCLS099I – DECEMBER 1982 – REVISED SEPTEMBER 2024



5.3 Thermal Information

	THERMAL METRIC	D (SOIC)	N (PDIP)	UNIT
		16 PINS	16 PINS	
R _{θJA}	Junction-to-ambient thermal resistance (1)	117.2	89.1	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	77.2	46.9	°C/W
R _{θJB}	Junction-to-board thermal resistance	75.6	47.4	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	38.1	11.8	°C/W
Ψјв	Junction-to-board characterization parameter	75.3	47	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

5.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER			Vee	1	_A = 25°C		SN54H0	C112	SN74HC112		UNIT
FARAMETER	TEST CONDITIONS		V _{cc}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			2V	1.9	1.998		1.9		1.9		
		I _{OH} = −20µA	4.5V	4.4	4.499		4.4		4.4		
V _{OH}	$V_{I} = V_{IH} \text{ or } V_{IL}$		6V	5.9	5.999		5.9		5.9		V
	$I_{OH} = -4mA$ $I_{OH} = -5.2mA$ $I_{OL} = 20\mu A$	I _{OH} = −4mA	4.5V	3.98	4.3			3.7		3.84	
		I _{OH} = −5.2mA	6V	5.48	5.8			5.2		5.34	
			2V		0.002	0.1		0.1		0.1	
		Ι _{ΟL} = 20μΑ	4.5V		0.001	0.1		0.1		0.1	
V _{OL}	$V_{I} = V_{IH} \text{ or } V_{IL}$		6V		0.001	0.1		0.1		0.1	V
		I _{OL} = 4mA	4.5V		0.17	0.26		0.4		0.33	
		I _{OL} = 5.2mA	6V		0.15	0.26		0.4		0.33	
lı lı	$V_{I} = V_{CC} \text{ or } 0$		6V		±0.1	±100		±1000		±1000	nA
I _{CC}	$V_{I} = V_{CC} \text{ or } 0, I_{O} = 0$		6V			4		80		40	μA
Ci			2V to 6V		3	10		10		10	pF

5.5 Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted)

			V _{cc}	T _A = 2	5°C	SN54HC	:112	SN74HC	:112	UNIT
			vcc	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
			2V		5		3.4		4	
f _{clock}	Clock frequency		4.5V		25		17		20	MHz
			6V		29		20		24	
		PRE or CLR low	2V	100		150		125		
			4.5V	20		30		25		
L.	Pulse duration		6V	17		25		21		ns
t _w	Puise duration	CLK high or low	2V	100		150		125		115
			4.5V	20		30		25		
			6V	17		25		21		



5.5 Timing Requirements (continued)

over recommended operating free-air temperature range (unless otherwise noted)

				T _A = 2	5°C	SN54H0	C112	SN74HC	2112	UNIT
			V _{cc}	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
			2V	100		150		125		
		Data (J, K)	4.5V	20		30		25		
	Setup time before CLK↓		6V	17		25		21		n 0
t _{su}		PRE or CLR inactive	2V	100		150		125		ns
			4.5V	20		30		25		
			6V	17		25		21		
			2V	0		0		0		
t _h	Hold time, data after CLK↓		4.5V	0		0		0		ns
			6V	0		0		0		

5.6 Switching Characteristics

over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Parameter Measurement Information)

PARAMETER	FROM	то	v	T⊿	= 25°C		SN54HC	:112	SN74HC	:112	UNIT	
PARAMETER	(INPUT)	(INPUT) (OUTPUT) ^V C	V _{cc}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
			2V	5	10		3.4		4			
f _{max}			4.5V	25	50		17		20		MHz	
			6V	29	60		20		24			
	PRE or CLR		2V		54	165		245		205		
		$\overline{\text{PRE}} \text{ or } \overline{\text{CLR}}$	Q or \overline{Q}	4.5V		16	33		49		41	
t .			6V		13	28		42		35	ns	
t _{pd}			2V		56	125		185		155	115	
	CLK	Q or \overline{Q}	4.5V		16	25		37		31		
			6V		13	21		31		26		
			2V		29	75		110		95		
t _t		Q or \overline{Q}	4.5V		9	15		22		19	ns	
			6V		8	13		19		16		

5.7 Operating Characteristics

T_A = 25°C

	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load	35	pF

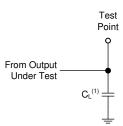


6 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1MHz, Z_O = 50 Ω , t_t < 6ns.

For clock inputs, f_{max} is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



(1) C_1 includes probe and test-fixture capacitance.



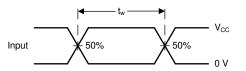


Figure 6-2. Voltage Waveforms, Standard CMOS Inputs Pulse Duration

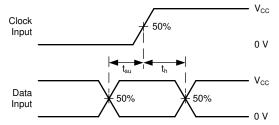


Figure 6-3. Voltage Waveforms, Standard CMOS Inputs Setup and Hold Times

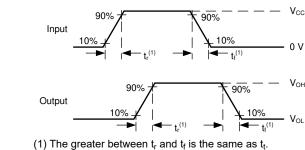
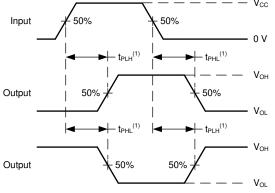


Figure 6-5. Voltage Waveforms, Input and Output Transition Times for Standard CMOS Inputs





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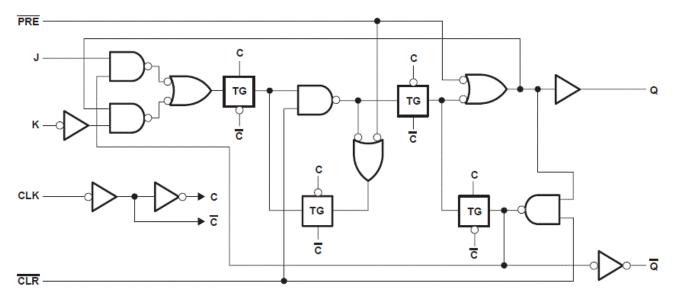


7 Detailed Description

7.1 Overview

The SNx4HC112 devices contain two independent J-K negative-edge-triggered flip-flops. A low level at the preset (PRE) or clear (CLR) inputs sets or resets the outputs, regardless of the levels of the other inputs. When PRE and CLR are inactive (high), data at the J and K inputs meeting the setup time requirements are transferred to the outputs on the negative-going edge of the clock (CLK) pulse. Clock triggering occurs at a voltage level and is not directly related to the fall time of the CLK pulse. Following the hold-time interval, data at the J and K inputs may be changed without affecting the levels at the outputs. These versatile flip-flops perform as toggle flip-flops by tying J and K high.

7.2 Functional Block Diagram



7.3 Device Functional Modes

Table 7-1. Function Table

		OUTI	PUTS			
PRE	CLR	CLK	J	К	Q	Q
L	Н	Х	Х	Х	Н	Н
н	L	Х	Х	Х	L	н
L	L	Х	Х	Х	H ⁽¹⁾	H ⁽¹⁾
Н	Н	Ļ	L	L	Q ₀	\overline{Q}_0
Н	Н	Ļ	Н	L	Н	L
Н	Н	Ļ	L	Н	L	Н
Н	Н	Ļ	Н	Н	Τος	ıgle
Н	Н	Н	Х	Х	Q ₀	\overline{Q}_0

(1) This configuration is non stable; that is, it does not persist when either PRE or CLR returns to its inactive (high) level.



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The 0.1µF and 1µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

8.2 Layout

8.2.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices, inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC} , whichever makes more sense for the logic function or is more convenient.



9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.3 Trademarks

TI E2E[™] is a trademark of Texas Instruments. All trademarks are the property of their respective owners.

9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision H (June 2022) to Revision I (September 2024)	Page
•	Updated the Device Information table to include package lead frame and body size	1
•	Changed V _{CC} unit from: mA to: V in the Absolute Maximum Ratings section	3

Changes from Revision G (February 2022) to Revision H (June 2022)	Page
 Junction-to-ambient thermal resistance values increased D was 73 is now 117.2 N was 67 is now 	10w 89 1 4

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
84088012A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	84088012A SNJ54HC 112FK	Samples
8408801EA	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8408801EA SNJ54HC112J	Samples
8408801FA	ACTIVE	CFP	W	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8408801FA SNJ54HC112W	Samples
JM38510/65305BEA	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 65305BEA	Samples
M38510/65305BEA	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 65305BEA	Samples
SN54HC112J	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	SN54HC112J	Samples
SN74HC112D	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-40 to 85	HC112	
SN74HC112DR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	HC112	Samples
SN74HC112DT	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-40 to 85	HC112	
SN74HC112N	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HC112N	Samples
SNJ54HC112FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	84088012A SNJ54HC 112FK	Samples
SNJ54HC112J	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8408801EA SNJ54HC112J	Samples
SNJ54HC112W	ACTIVE	CFP	W	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8408801FA SNJ54HC112W	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



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⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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OTHER QUALIFIED VERSIONS OF SN54HC112, SN74HC112 :

• Catalog : SN74HC112

• Military : SN54HC112

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications



SN74HC112DR

SOIC

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PACKAGE MATERIALS INFORMATION

K0

(mm)

2.1

P1

(mm)

8.0

w

(mm)

16.0

Pin1

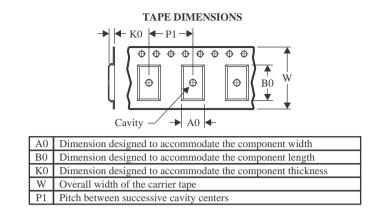
Quadrant

Q1

25-Sep-2024

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



330.0

16.4

6.5

10.3

*All dimensions are nominal							
Device	Package Type	Package Drawing		Reel Diameter	Reel Width	A0 (mm)	B0 (mm)
				(mm)	W1 (mm)		

16

2500

D



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PACKAGE MATERIALS INFORMATION

25-Sep-2024



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HC112DR	SOIC	D	16	2500	356.0	356.0	35.0

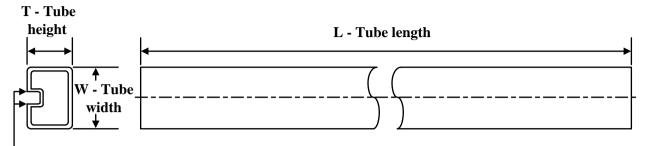


PACKAGE MATERIALS INFORMATION

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TUBE



- B - Alignment groove width

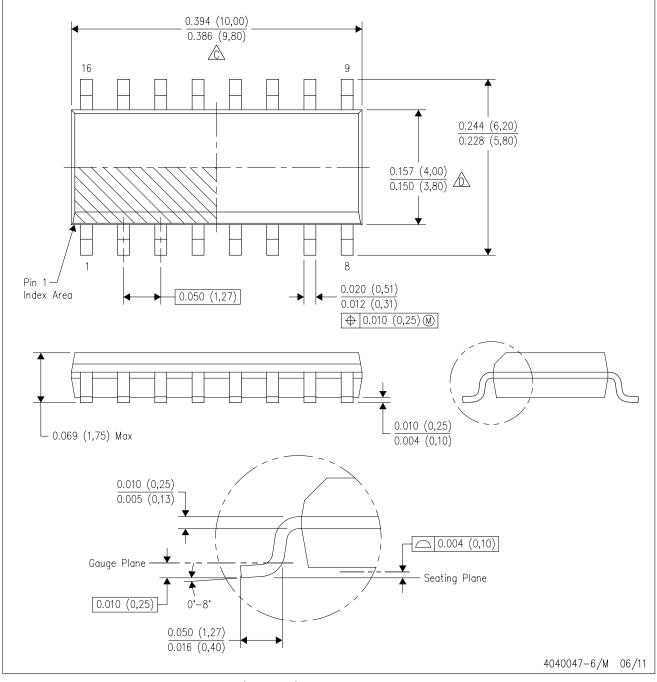
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
84088012A	FK	LCCC	20	55	506.98	12.06	2030	NA
8408801FA	W	CFP	16	25	506.98	26.16	6220	NA
SN74HC112N	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC112N	N	PDIP	16	25	506	13.97	11230	4.32
SNJ54HC112FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54HC112W	W	CFP	16	25	506.98	26.16	6220	NA

MECHANICAL DATA

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

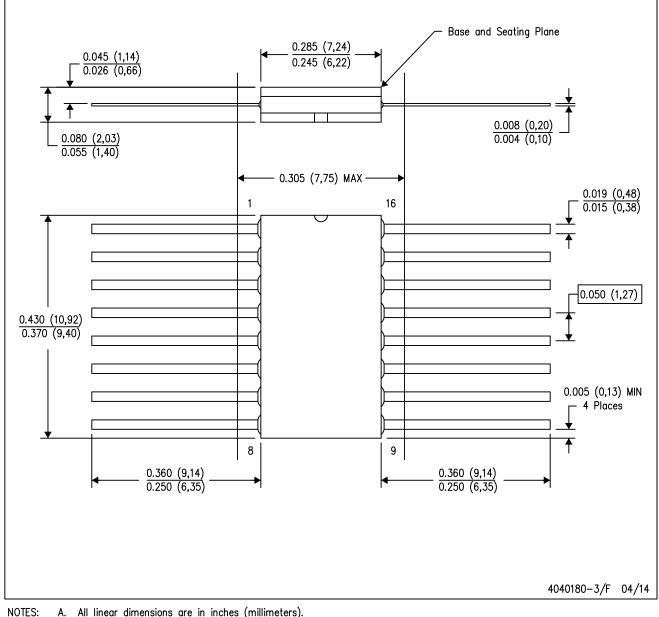
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



MECHANICAL DATA

W (R-GDFP-F16)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only.
 - E. Falls within MIL STD 1835 GDFP2-F16



GENERIC PACKAGE VIEW

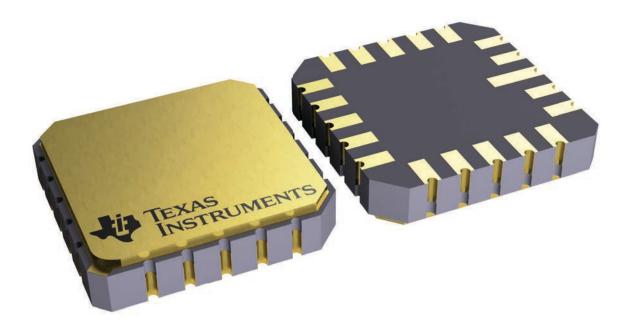
FK 20

LCCC - 2.03 mm max height

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

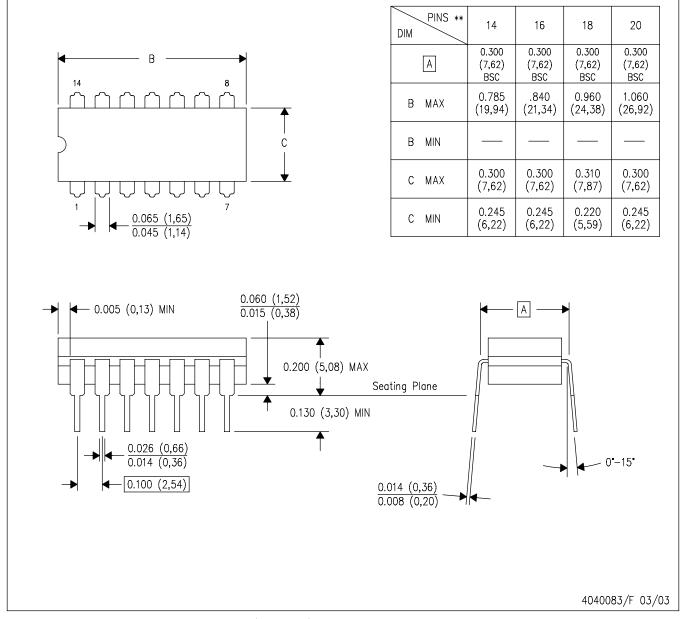




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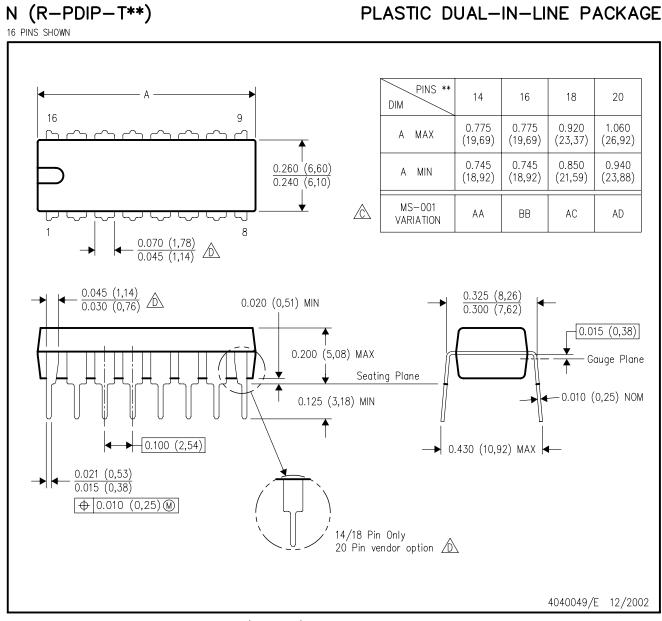
J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



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